# NSN 5962-01-336-7012

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# **Overall Height:**

0.400 inches

#### **Body Length:**

1.280 inches

## Body Width:

Between 0.220 inches and 0.310 inches

#### **Body Height:**

Between 0.140 inches and 0.185 inches

## **Maximum Power Dissipation Rating:**

1.0 watts

## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **Features Provided:**

Hermetically sealed and burn in and monolithic and positive outputs

#### Inclosure Material:

Ceramic

#### Inclosure Configuration:

Dual-in-line

## Output Logic Form:

Complementary-metal oxide-semiconductor logic

#### **Input Circuit Pattern:**

14 input

## **Case Outline Source And Designator:**

D-9 mil-m-38510

## **Current Rating Per Characteristic:**

120.00 milliamperes total supply

## **Terminal Surface Treatment:**

Solder

# Voltage Rating And Type Per Characteristic:

7.0 volts power source

# Time Rating Per Chacteristic:

40.00 nanoseconds propagation delay time, low to high level output and 40.00 nanoseconds propagation delay time, high to low level output

## Memory Device Type:

Prom

# Memory Capacity:

Unknown

# Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

# Terminal Type And Quantity:

24 printed circuit

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Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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